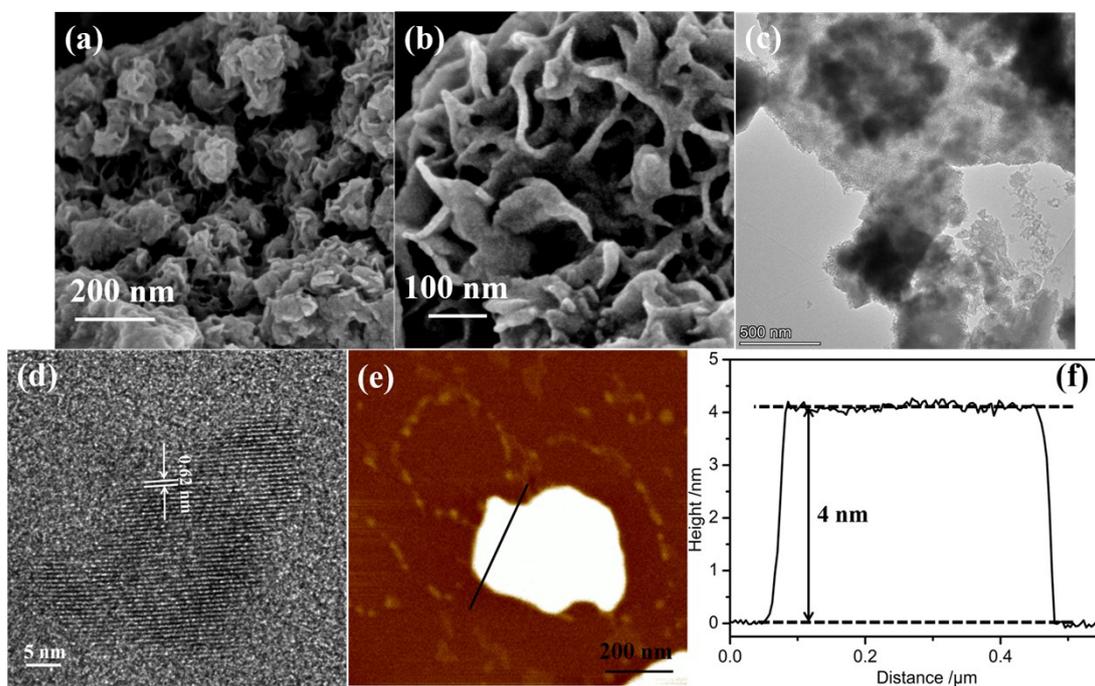


## Defect-rich ultrathin MoS<sub>2</sub>/rGO nanosheets electrocatalyst for oxygen reduction reaction

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**Figure S1** (a) Low-magnification SEM image, (b) High-magnification SEM image, (c) TEM image, (d) HRTEM image, (e) AFM image and (f) height profiles from sections as indicated by the black line of MoS<sub>2</sub>.

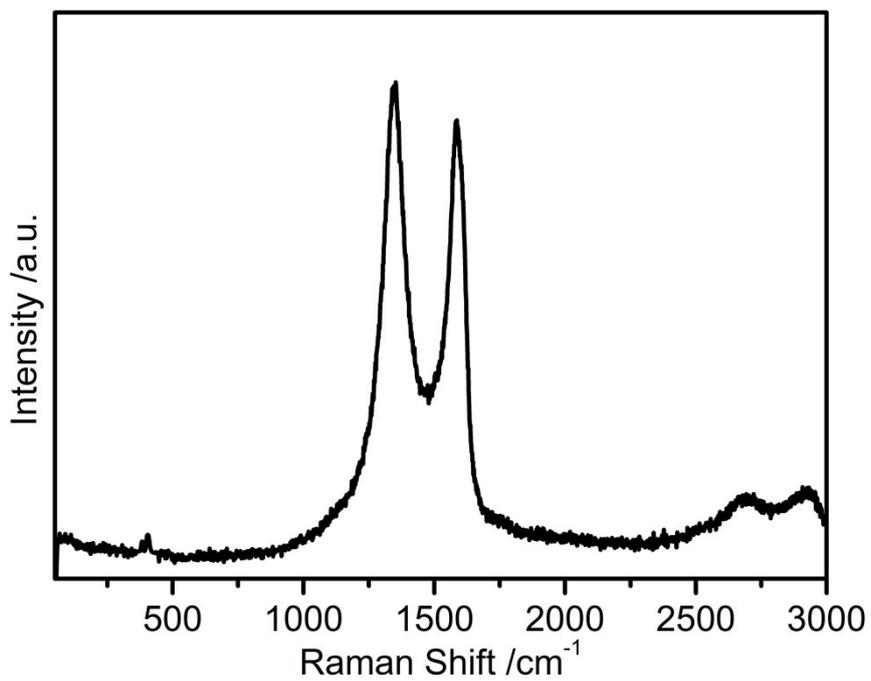


Figure S2 Raman spectrum of MoS<sub>2</sub>/rGO

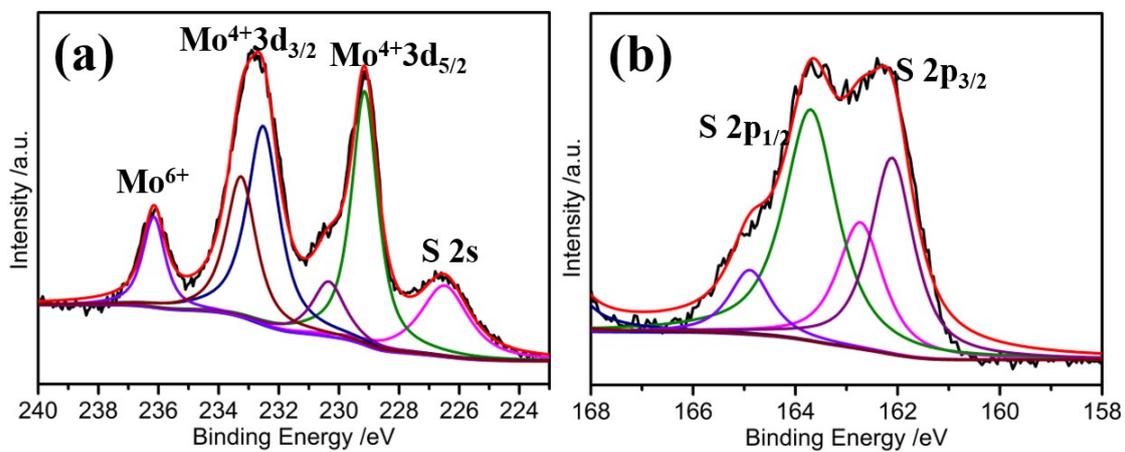
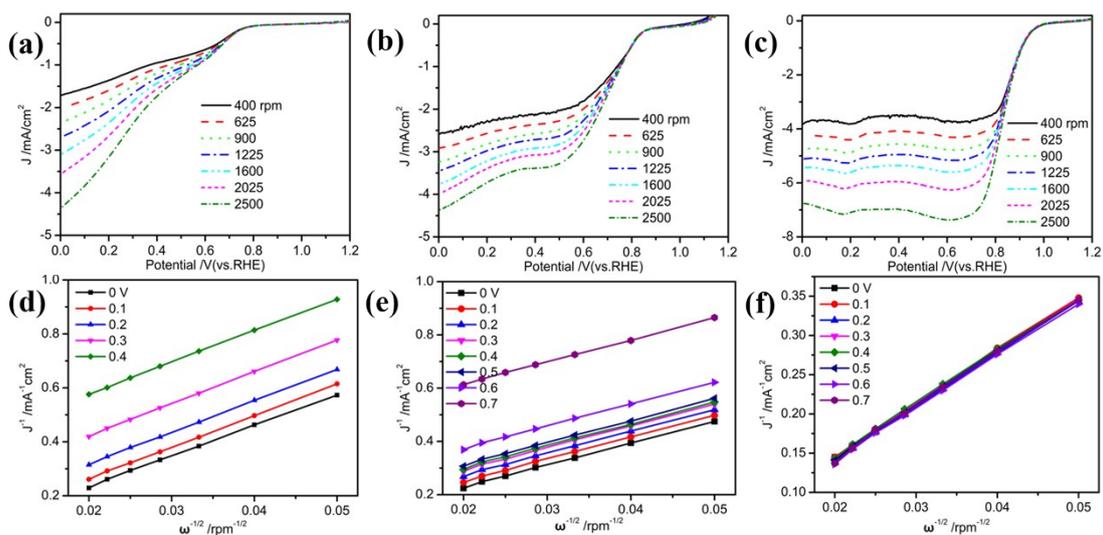
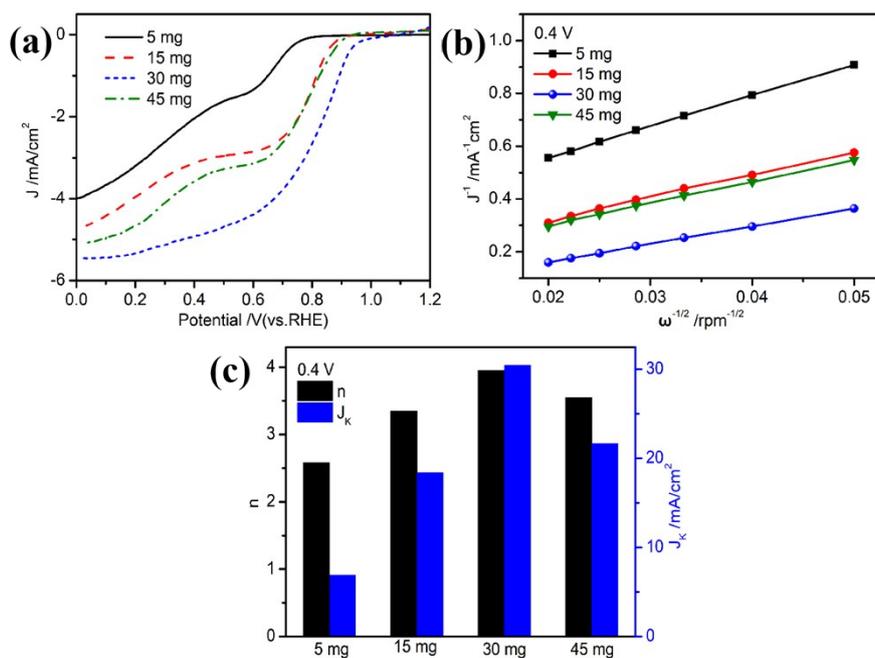


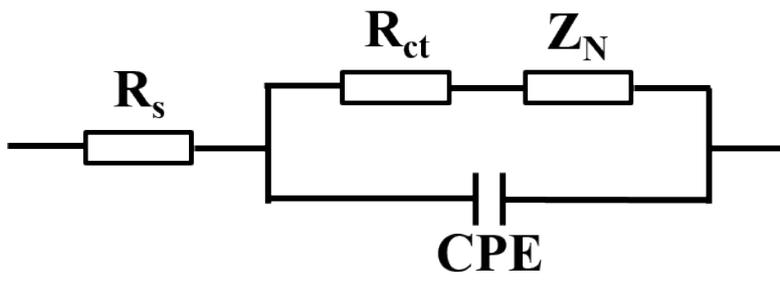
Figure S3 High-resolution XPS profiles of (a) Mo3d and (b) S2p of MoS<sub>2</sub>.



**Figure S4** (a,d) LSV and calculated K–L plots of MoS<sub>2</sub>, (b,e) LSV and calculated K–L plots of rGO, (c,f) LSV and calculated K–L plots of Pt/C.



**Figure S5** (a) Linear sweep voltammetry (LSV) of MoS<sub>2</sub>/rGO samples with different graphene content in O<sub>2</sub>-saturated 0.1 M KOH at a scan rate of 10 mV·s<sup>-1</sup> with an RDE rotation rate of 1600 rpm. (b) K–L plots at 0.4 V of MoS<sub>2</sub>/rGO samples with different graphene content. (c) transferred electron number  $n$  and  $J_k$  of the ORR for MoS<sub>2</sub>/rGO samples with different graphene content.



**Figure S6** The equivalent circuit model of EIS.